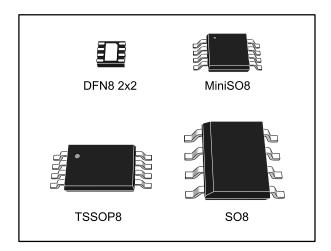


LM158, LM258, LM358

Low-power dual operational amplifiers

Datasheet - production data



Features

- Frequency compensation implemented internally
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)
- Very low supply current per channel essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)
- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common-mode voltage range includes negative rails
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to (V_{CC}⁺ - 1.5 V)

Related products

See LM158W for enhanced ESD ratings

Description

These circuits consist of two independent, highgain, internally frequency-compensated op amps, specifically designed to operate from a single power supply over a wide range of voltages. The low-power supply drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits, which can now be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard 5 V, which is used in logic systems and will easily provide the required interface electronics with no additional power supply.

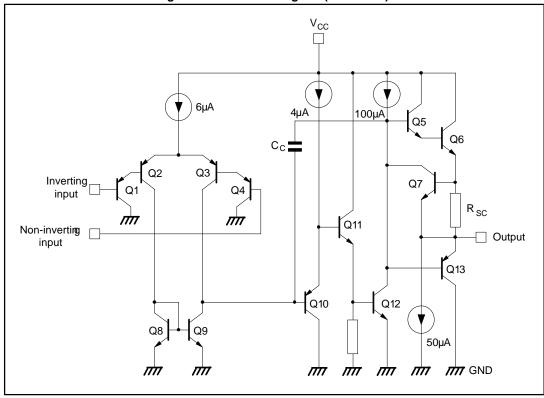
In linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

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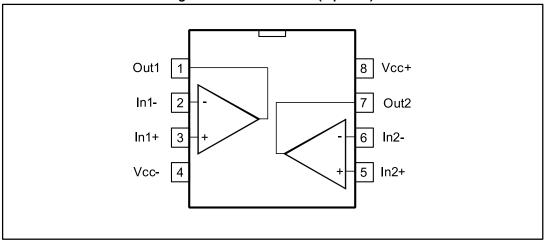
1 Schematic diagram

Figure 1: Schematic diagram (1/2 LM158)



2 Package pin connections

Figure 2: Pin connections (top view)



1. The exposed pad of the DFN8 2x2 can be left floating or connected to ground

3 Absolute maximum ratings

Table 1: Absolute maximum ratings

Symbol	Parameter	Parameter					
Vcc	Supply voltage		±16 or 32				
Vi	Input voltage			32		V	
Vid	Differential input voltage			32			
	Output short-circuit duration (1)			Infinite			
l _{in}	Input current (2)		_	n DC or 50 mA ycle = 10 %, T	_	mA	
Toper	Operating free-air temperature range		-55 to 125	-40 to 105	0 to 70		
T _{stg}	Storage temperature range		-65 to 150			°C	
Tj	Maximum junction temperature		150				
		SO8	125				
	Thermal resistance junction to ambient (3)	MiniSO8	190				
R _{thja}		DFN8 2x2	57				
		TSSOP8	120			°C/W	
		SO8	40				
R _{thjc}	Thermal resistance junction to case (3)	MiniSO8		39		1	
			37				
	HBM: human body model (4)	300			.,,		
ESD	MM: machine model ⁽⁵⁾	200			V		
	CDM: charged device model ⁽⁶⁾		1.5				

⁽¹⁾Short-circuits from the output to V_{CC} can cause excessive heating if $V_{CC} > 15$ V. The maximum output current is approximately 40 mA independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short circuits on all amplifiers.

 $^{^{(2)}}$ This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward-biased and thereby acting as input diode clamp. In addition to this diode action, there is NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the Vcc voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output is restored for input voltages above -0.3 V.

⁽³⁾Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.

⁽⁴⁾Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

 $^{^{(5)}}$ Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.

⁽⁶⁾Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2: Operating conditions

Symbol	Parameter		Value	Unit
Vcc	Supply voltage		3 to 30	V
Vicm	Common mode input voltage range (1)	(Vcc ⁻) - 0.3 to (Vcc ⁺) - 1.5	V	
		LM158	-55 to 125	
T _{oper}	Operating free air temperature range	LM258	-40 to 105	°C
		LM358	0 to 70	

⁽¹⁾When used in comparator, the functionality is guaranteed as long as at least one input remains within the operating common mode voltage range.

4 Electrical characteristics

Table 3: Electrical characteristics for VCC+ = 5 V, VCC- = Ground, Vo = 1.4 V, Tamb = 25 $^{\circ}$ C (unless otherwise specified)

Symbol		Parameter	Min.	Тур.	Max.	Unit
		LM158A			2	
	Lancet affant contains (1)	LM258A, LM358A		1	3	
	Input offset voltage (1)	LM158, LM258			5	
V_{io}		LM358		2	7	mV
		LM158A, LM258A, LM358A			4	
	$T_{min} \le T_{amb} \le T_{max}$	LM158, LM258			7	
		LM358			9	
A) / /A T	1	LM158A, LM258A, LM358A		7	15	1//00
$\Delta V_{io}/\Delta T$	Input offset voltage drift	LM158, LM258, LM358		7	30	μV/°C
		LM158A, LM258A, LM358A		2	10	
	Input offset current	LM158, LM258, LM358		2	30	1
l _{io}	T 4T 4T	LM158A, LM258A, LM358A			30	nA .
	$T_{min} \le T_{amb} \le T_{max}$	LM158, LM258, LM358			40	
A1 /AT		LM158A, LM258A, LM358A		10	200	A /0.0
ΔI _{io} /ΔΤ	Input offset current drift	LM158, LM258, LM358		10	300	pA/°C
	Input bias current (2)	LM158A, LM258A, LM358A		20	50	- nA
		LM158, LM258, LM358		20	150	
lib	T 4T 4T	LM158A, LM258A, LM358A			100	nA
	$T_{min} \le T_{amb} \le T_{max}$	LM158, LM258, LM358			200	
A _{vd}	Large signal voltage	$V_{CC}^+ = 15 \text{ V}, R_L = 2 \text{ k}\Omega,$ $V_0 = 1.4 \text{ V} \text{ to } 11.4 \text{ V}$	50	100		V/mV
	gain	$T_{min} \le T_{amb} \le T_{max}$	25			
O) (D	Supply voltage rejection	V_{CC}^+ = 5 V to 30 V, $R_s \le 10 \text{ k}\Omega$	65	100		-10
SVR	ratio	$T_{min} \le T_{amb} \le T_{max}$	65			dB
	Supply current, all amp,	$T_{min} \le T_{amb} \le T_{max} V_{CC}^+ = 5 V$		0.7	1.2	A
Icc	no load	$T_{min} \le T_{amb} \le T_{max} \ V_{CC}^+ = 30 \ V$			2	mA
	Input common mode	$V_{CC}^{+} = 30 \text{ V}^{(3)}$	0		(Vcc+) - 1.5	V
V_{icm}	voltage range	$T_{min} \le T_{amb} \le T_{max}$	0		(Vcc+) - 2	V
CMD	Common mode	R _s ≤ 10 kΩ	70	85		J.
CMR	rejection ratio	$T_{min} \le T_{amb} \le T_{max}$	60			dB
Isource	Output current source	$V_{CC}^+ = 15 \text{ V}, V_0 = 2 \text{ V}, V_{id} = 1 \text{ V}$	20	40	60	mA
		$V_{CC}^+ = 15 \text{ V}, V_0 = 2 \text{ V}, V_{id} = -1 \text{ V}$	10	20		mA
Isink	Output sink current	$V_{cc}^+ = 15 \text{ V}, V_o = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	12	50		μA

Electrical characteristics

LM158, LM258, LM358

Symbol	Parameter			Тур.	Max.	Unit
		$R_L = 2 \text{ k}\Omega, V_{CC}^+ = 30 \text{ V}$	26	27		
	High level output	$T_{min} \le T_{amb} \le T_{max}$	26			V
Vон	voltage	$R_L = 10 \text{ k}\Omega, V_{CC}^+ = 30 \text{ V}$	27	28		V
		$T_{min} \le T_{amb} \le T_{max}$	27			
V	Law layed autout valtage	$R_L = 10 \text{ k}\Omega$		5	20	\/
Vol	Low level output voltage	$T_{min} \le T_{amb} \le T_{max}$			20	mV
SR	Slew rate	$\begin{split} V_{CC}{}^{+} &= 15 \text{ V}, \text{ V}_i = 0.5 \text{ to } 3 \text{ V}, \\ R_L &= 2 \text{ k}\Omega, \text{ C}_L = 100 \text{ pF}, \\ \text{unity gain} \end{split}$	0.3	0.6		V/µs
GBP	Gain bandwidth product	$\begin{split} &V_{CC}{}^{+}=30 \text{ V, f}=100 \text{ kHz,} \\ &V_{in}=10 \text{ mV, R}_{L}=2 \text{ k}\Omega, \\ &C_{L}=100 \text{ pF} \end{split}$	0.7	1.1		MHz
THD	Total harmonic distortion	$ f = 1 \text{ kHz, } A_V = 20 \text{ dB, } R_L = 2 \text{ k}\Omega, \\ V_o = 2 \text{ V}_{pp}, C_L = 100 \text{ pF,} \\ V_O = 2 \text{ V}_{pp} $		0.02		%
en	Equivalent input noise voltage	$ f = 1 \text{ kHz}, R_s = 100 \ \Omega, $ $V_{CC}{}^+ = 30 \ V $		55		<u>nV</u> √Hz
V ₀₁ /V ₀₂	Channel separation (4)	1 kHz ≤ f ≤ 20 kHz		120		dB

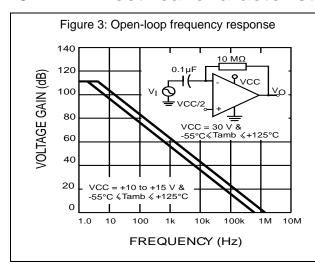
 $^{^{(1)}}$ Vo = 1.4 V, Rs = 0 Ω , 5 V < Vcc⁺ < 30 V, 0 < Vic < Vcc⁺ - 1.5 V

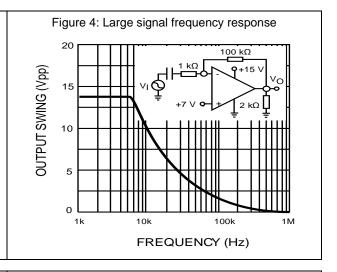
⁽²⁾The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so there is no change in the load on the input lines.

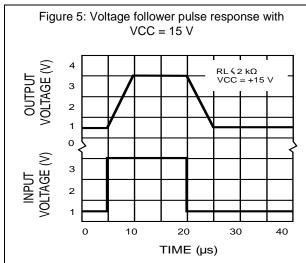
 $^{^{(3)}}$ The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is (V_{CC}^+) - 1.5 V, but either or both inputs can go to 32 V without damage.

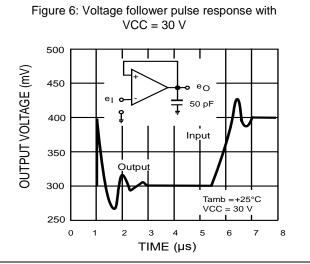
⁽⁴⁾Due to the proximity of external components, ensure that stray capacitance between these external parts does not cause coupling. Typically, this can be detected because this type of capacitance increases at higher frequencies.

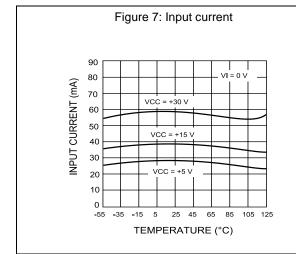
5 Electrical characteristic curves











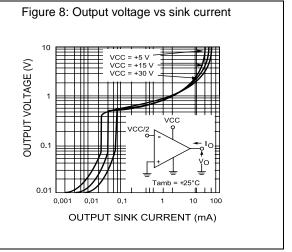
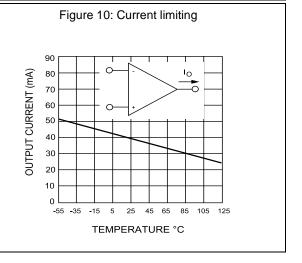


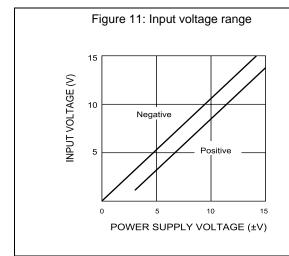
Figure 9: Output voltage vs source current

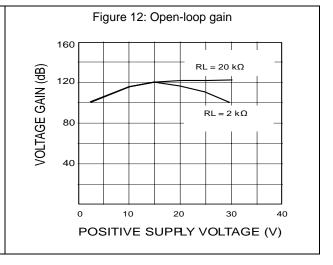
8
7
4
VCC/2

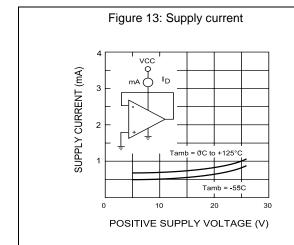
V

OUTPUT SOURCE CURRENT (mA)









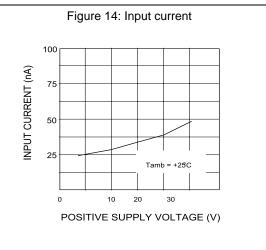
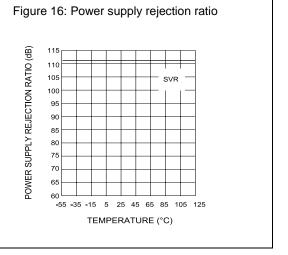
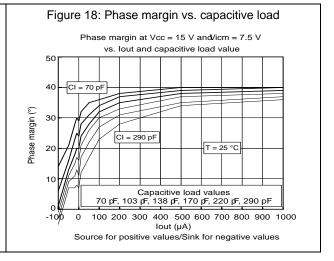


Figure 15: Gain bandwidth product

1.5
1.35
1.2
1.05
0.9
0.75
0.6
0.45
0.45
0.3
0.15
0.55 -35 -15 5 25 45 65 85 105 125

TEMPERATURE (°C)

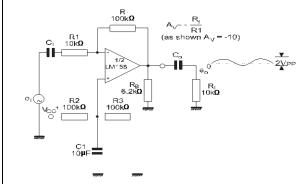




6 Typical applications

Single supply voltage $V_{CC} = 5 V_{DC}$.

Figure 19: AC-coupled inverting amplifier



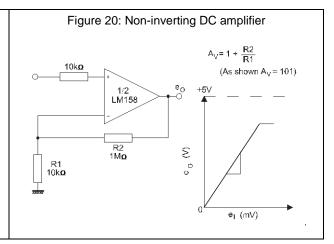
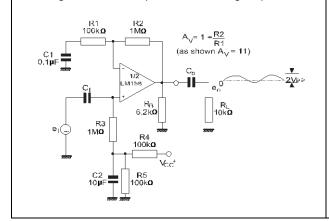


Figure 21: AC-coupled non-inverting amplifier



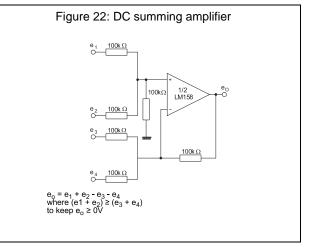


Figure 23: High input Z, DC differential amplifier

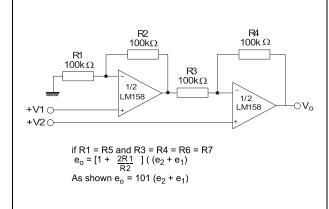


Figure 24: High input Z adjustable gain DC instrumentation amplifier

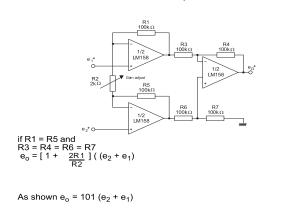
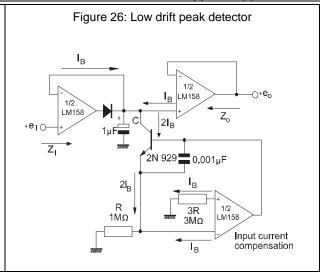
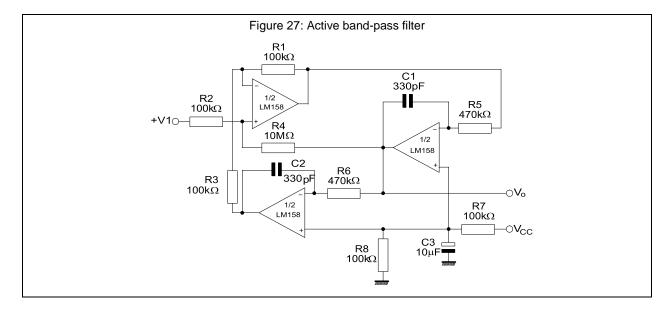


Figure 25: Using symmetrical amplifiers to reduce input current -1/2 -⊝ e_o LM158 $I_1 \downarrow I_B$ +e₁○-I_B 2N 929 **=**0.001μF I_B I_{B} 1/2 LM158 ЗМΩ Input current compensation IB 1.5ΜΩ





7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

7.1 SO8 package information

Figure 28: SO8 package outline

Table 4: SO8 mechanical data

	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max		
А			1.75			0.069		
A1	0.10		0.25	0.004		0.010		
A2	1.25			0.049				
b	0.28		0.48	0.011		0.019		
С	0.17		0.23	0.007		0.010		
D	4.80	4.90	5.00	0.189	0.193	0.197		
Е	5.80	6.00	6.20	0.228	0.236	0.244		
E1	3.80	3.90	4.00	0.150	0.154	0.157		
е		1.27			0.050			
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
L1		1.04			0.040			
k	1°		8°	1°		8°		
ccc			0.10			0.004		

7.2 MiniSO8 package information

PIN 1 DENTIFICATION

PIN 1 DENTIFICATION

PLANE

COLUMN TO THE PLANE

CO

Figure 29: MiniSO8 package outline

Table 5: MiniSO8 mechanical data

	Dimensions							
Ref.	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.1			0.043		
A1	0		0.15	0		0.006		
A2	0.75	0.85	0.95	0.030	0.033	0.037		
b	0.22		0.40	0.009		0.016		
С	0.08		0.23	0.003		0.009		
D	2.80	3.00	3.20	0.11	0.118	0.126		
Е	4.65	4.90	5.15	0.183	0.193	0.203		
E1	2.80	3.00	3.10	0.11	0.118	0.122		
е		0.65			0.026			
L	0.40	0.60	0.80	0.016	0.024	0.031		
L1		0.95			0.037			
L2		0.25			0.010			
k	0°		8°	0°		8°		
ccc			0.10			0.004		

7.3 DFN8 2x2 package information

Figure 30: DFN8 2x2 package outline

Table 6: DFN8 2x2 mechanical data

	Dimensions							
Ref.		Millimeters	1	Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	0.51	0.55	0.60	0.020	0.022	0.024		
A1			0.05			0.002		
А3		0.15			0.006			
b	0.18	0.25	0.30	0.007	0.010	0.012		
D	1.85	2.00	2.15	0.073	0.079	0.085		
D2	1.45	1.60	1.70	0.057	0.063	0.067		
Е	1.85	2.00	2.15	0.073	0.079	0.085		
E2	0.75	0.90	1.00	0.030	0.035	0.039		
е		0.50			0.020			
L		0.3	0.425		0.012	0.017		
ddd			0.08			0.003		

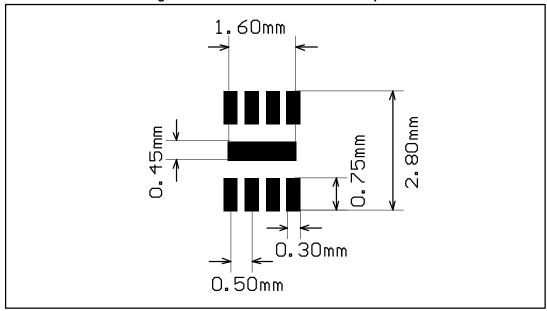


Figure 31: DFN8 2x2 recommended footprint

7.4 TSSOP8 package information

PIN 1 DENIFICATION

PLANE

PLA

Figure 32: TSSOP8 package outline

Table 7: TSSOP8 mechanical data

	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.2			0.047	
A1	0.05		0.15	0.002		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.012	
С	0.09		0.20	0.004		0.008	
D	2.90	3.00	3.10	0.114	0.118	0.122	
Е	6.20	6.40	6.60	0.244	0.252	0.260	
E1	4.30	4.40	4.50	0.169	0.173	0.177	
е		0.65			0.0256		
k	0°		8°	0°		8°	
L	0.45	0.60	0.75	0.018	0.024	0.030	
L1		1			0.039		
aaa		0.1			0.004		

8 Ordering information

Table 8: Order codes

	_			
Order code	Temperature range	Package	Packaging	Marking
LM158QT	-55 °C to 125 °C	DFN8 2x2		K4A
LM158DT	-55 'C to 125 'C	SO8		158
LM258ADT		SO8		258A
LM258AYDT (1)		SO8, automotive grade		258AY
LM258DT	40.00 +- 405.00	SO8		258
LM258APT	-40 °C to 105 °C	TSSOP8	Tape and reel	258A
LM258AST		MiniSO8		K408
LM258QT		DFN8 2x2		K4C
LM358DT		SO8		358
LM358YDT (1)		SO8, automotive grade		358Y
LM358ADT		SO8		358A
LM358PT	0 °C to 70 °C	TSSOP8		358
LM358APT		1350P6		358A
LM358ST		MiniSO8		K405
LM358AST		MINIOR	l	K404
LM358QT		DFN8 2x2		K4E

 $^{^{(1)}}$ Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

9 Revision history

Table 9: Document revision history

Date	Revision	Changes
01-Jul- 2003	1	First release.
02-Jan-2005	2	R _{thja} and T _j parameters added in AMR Table 1: "Absolute maximum ratings".
01-Jul-2005	3	ESD protection inserted in Table 1: "Absolute maximum ratings".
05-Oct-2006	4	Added Figure 17: Phase margin vs. capacitive load.
30-Nov-2006	5	Added missing ordering information.
25-Apr-2007	6	Removed LM158A, LM258A and LM358A from document title. Corrected error in MiniSO-8 package data. L1 is 0.004 inch. Added automotive grade order codes in Section 7: "Ordering information".
12-Feb-2008	7	Corrected V_{CC} max (30 V instead of 32 V) in operating conditions. Changed presentation of electrical characteristics table. Deleted V_{opp} parameter in electrical characteristics table. Corrected miniSO-8 package information. Corrected temperature range for automotive grade order codes. Updated automotive grade footnotes in order codes table.
26-Aug-2008	8	Added limitations on input current in Table 1: "Absolute maximum ratings". Corrected title for Figure 11. Added E and L1 parameters in Table 4: "SO8 package mechanical data". Changed Figure 31: "TSSOP8 package mechanical drawing".
02-Sep-2011	9	In Section 6: "Package information", added: DFN8 2 x 2 mm package mechanical drawing DFN8 2 x 2 mm recommended footprint DFN8 2 x 2 mm order codes.
06-Apr-2012	10	Removed order codes LM158YD, LM258AYD, LM258YD and LM358YD from Table 8: "Order codes".
11-Jun-2013	11	Table 8: "Order codes": removed order codes LM158D, LM158YDT, LM258YDT, and LM258AD; added automotive grade qualification to order codes LM258ATDT and LM358YDT; updated marking for order codes LM158DT and LM258D/LM258DT; updated temperature range, packages, and packaging for several order codes.
20-Jun-2014	12	Removed DIP8 package Corrected typos (W replaced with Ω, £ replaced with ≤) Updated Features Added Related products Table 3: replaced DV _{io} with ΔV _{io} /ΔT and DI _{io} with ΔI _{io} /ΔT. Updated Table 7 for exposed pad dimensions Table 8: "Order codes": removed order codes LM258YPT and LM258AYPT; removed all order codes for devices with tube packing; added package code (NB) to DFN8 2x2 package.

Date	Revision	Changes
		Updated document layout Updated name of the "DFN8 2x2 (NB) mm" package to "DFN8 2x2" everywhere in datasheet.
13-Nov-2015	13	Section 2: "Package pin connections": placed the package's pinout in this section and added note about exposed pad.
		Table 8: "Order codes": removed order codes LM258ST, LM358YPT, and LM358AYPT.
24-Aug-2016	14	Table 6: "DFN8 2x2 mechanical data": added typ. value for "L" dimension.

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